NSN 5961-01-355-0507



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-355-0507 **Inclosure Material:** Metal or plastic **Overall Length:** 0.750 inches **Overall Height:** 0.620 inches **Overall Width:** 0.750 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Component Name And Quantity:** 8 semiconductor device diode **Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case and quality assurance level tx **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 6.0 working peak reverse voltage 1st semiconductor device diode6.0 working peak reverse voltage 2nd semiconductor device diode36.8 working peak reverse voltage 3rd semiconductor device diode36.8 working peak reverse voltage 4th semiconductor device diode5.0 working peak reverse voltage 5th semiconductor device diode5.0 working peak reverse voltage 5th transistorerr-070err-070 **Current Rating Per Characteristic:** 1000.00 microamperes forward current, average peak 1st semiconductor device diode1000.00 microamperes forward current, average peak 2nd semiconductor device diode5.00 microamperes forward current, average peak 3rd semiconductor device diode5.00 microamperes forward current, average peak 4th semiconductor device diode300.00 microamperes forward current, average peak 5th semiconductor device diode300.00 microamperes forward current, average peak 5th transistorerr-070err-070 **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 8 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Fiig:

No

Demilitarization: